Tool ID: 119 Tool Location: 103

## **Equipment Information Sheet**

# **CMOS Undoped Poly - E3**

Manager: Phil Infante 607-254-4926 Backup: Aaron Windsor 607-254-4831

Calls to staff phones will be automatically forwarded to their cell phones during accessible hours. At other times

leave a message or send them an email.

## **SAFETY**

• The furnaces are run at elevated temperatures of 400-1200°C and use flammable, toxic, and corrosive gases.

## **USAGE RESTRICTIONS**

- No changing of gas flows or process parameters without staff approval
- Max process temperature of 650 C

## SCHEDULING/SIGN-UP RESTRICTIONS

Minimum Tool Time: 90 minutes

 Reservation blocks greater than 8 hrs must be cleared by a MOS staff person prior to reserving the time

### MATERIALS COMPATIBILITY CATEGORY

# Tool Category 1:Restriced Silicon Based Materials Only Allowed Silicon Based Materials only (Si, SiC, SiO 2 substrates) All Furnace grown or deposited films No ALD films PECVD Films No Glass Substrates No III/V Compound Semiconductors No Deep Silicon Etched Samples (versaline, Unaxis) No Organic/Biology Molecules prepared-with or without Salt buffers

## **Additional Material Restrictions and Exceptions**

- MOS CLEAN required prior to use
- Only use MOS designated holders, wands and tweezers

Last Updated: 03/20/2019